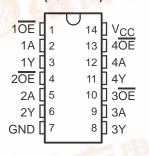
捷多邦,专业PCB打样**ISN54LV时25A**中**SN74LV125A** QUADRUPLE BUS BUFFER GATES

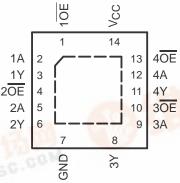
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- 2-V to 5.5-V V_{CC} Operation
- Max tpd of 6 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- **Support Mixed-Mode Voltage Operation on All Ports**
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

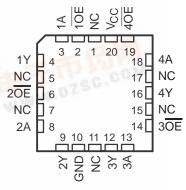
SN54LV125A . . . J OR W PACKAGE SN74LV125A . . . D, DB, DGV, N, NS, OR PW PACKAGE (TOP VIEW)



SN74LV125A . . . RGY PACKAGE (TOP VIEW)



SN54LV125A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

description/ordering information

The 'LV125A quadruple bus buffer gates are designed for 2-V to 5.5-V V_{CC} operation.

These devices feature independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (\overline{OE}) input is high.

ORDERING INFORMATION

TA	PACK	AGET	ORDERABLE PART NUMBER	TOP-SIDE MARKING
1 1 m	PDIP – N	Tube of 25	SN74LV125AN	SN74LV125AN
AL AL	QFN – RGY	Reel of 1000	SN74LV125ARGYR	LV125A
	0010 D	Tube of 50	SN74LV125AD	11/4054
	SOIC - D	Reel of 2500	SN74LV125ADR	LV125A
4000 4 0500	SOP - NS	Reel of 2000	SN74LV125ANSR	74LV125A
–40°C to 85°C	SSOP – DB	Reel of 2000	SN74LV125ADBR	LV125A
		Tube of 90	SN74LV125APW	41.44
	TSSOP - PW	Reel of 2000	SN74LV125APWR	LV125A
	- STAP	Reel of 250	SN74LV125APWT	
	TVSOP - DGV	Reel of 2000	SN74LV125ADGVR	LV125A
The same	CDIP – J	Tube of 25	SNJ54LV125AJ	SNJ54LV125AJ
_55°C to 125°C	CFP – W	Tube of 150	SNJ54LV125AW	SNJ54LV125AW
	LCCC – FK	Tube of 55	SNJ54LV125AFK	SNJ54LV125AFK

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

TEXAS

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of



SN54LV125A, SN74LV125A QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

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description/ordering information (continued)

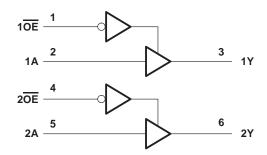
To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

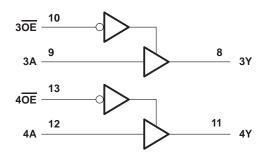
These devices are fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

FUNCTION TABLE (each buffer)

INP	UTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	X	Z

logic diagram (positive logic)





Pin numbers shown are for the D, DB, DGV, J, N, NS, PW, RGY, and W packages.



SN54LV125A, SN74LV125A QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	-0.5 V to 7 V
Output voltage range, VO (see Notes 1 and 2)	$0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{ K }(V_{ I } < 0)$	–20 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	$\dots \dots \pm 35 \text{ mA}$
Continuous current through V _{CC} or GND	$\dots \dots \pm 70 \text{ mA}$
Package thermal impedance, θ _{JA} (see Note 3): D package	86°C/W
(see Note 3): DB package	
(see Note 3): DGV package	127°C/W
(see Note 3): N package	80°C/W
(see Note 3): NS package	
(see Note 3): PW package	
(see Note 4): RGY package	
Storage temperature range, T _{stq}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.

SN54LV125A, SN74LV125A QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS SCES124L - DECEMBER 1997 - REVISED APRIL 2005

recommended operating conditions (see Note 5)

			SN54L	_V125A	SN74L	V125A	
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
. ,	LPak Java Panatasakana	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	V _{CC} × 0.7		$V_{CC} \times 0.7$.,
VIH	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	V _{CC} ×0.7		$V_{CC} \times 0.7$		V
		V _{CC} = 4.5 V to 5.5 V	V _{CC} ×0.7		$V_{CC} \times 0.7$		
		V _{CC} = 2 V		0.5		0.5	
1/	Law lawal input waltana	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
VIL	Low-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	
VI	Input voltage		0	5.5	0	5.5	V
\/ -	Output valta na	High or low state	0	VCC VCC	0	VCC	V
VO	Output voltage	3-state	0 ,	5.5	0	5.5	V
		V _{CC} = 2 V	5	-50		-50	μΑ
	High-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	-2		-2	
ЮН	nign-ievei output current	$V_{CC} = 3 V \text{ to } 3.6 V$	Q	-8		-8	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-16		-16	
		$V_{CC} = 2 V$		50		50	μΑ
	Low lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	
lOL	Low-level output current	$V_{CC} = 3 V \text{ to } 3.6 V$		8		8	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		16		16	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		200		200	
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3 V \text{ to } 3.6 V$		100		100	ns/V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		20		20	
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 5: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	.,,	SN5	4LV125A	SN7	4LV125A	1	LINUT	
PARAMETER	TEST CONDITIONS	vcc	MIN	TYP MAX	MIN	TYP	MAX	UNIT	
	$I_{OH} = -50 \mu A$	2 V to 5.5 V	V _{CC} -0.1		V _{CC} -0.1				
V	$I_{OH} = -2 \text{ mA}$	2.3 V	2		2			V	
VOH	I _{OH} = -8 mA	3 V	2.48		2.48			V	
	I _{OH} = -16 mA	4.5 V	3.8	N.	3.8				
	I _{OL} = 50 μA	2 V to 5.5 V		0.	1		0.1		
V = :	I _{OL} = 2 mA	2.3 V		0.	1		0.4	V	
VOL	I _{OL} = 8 mA	3 V		0.4	1		0.44	V	
	I _{OL} = 16 mA	4.5 V	770	0.5	5		0.55		
lį	V _I = 5.5 V or GND	0 to 5.5 V	0%	±	1		±1	μΑ	
loz	$V_O = V_{CC}$ or GND	5.5 V	Q	±	5		±5	μΑ	
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V		2)		20	μΑ	
l _{off}	V_I or $V_O = 0$ to 5.5 V	0			5		5	μΑ	
0.	V. V or CND	3.3 V		1.6		1.6	·		
C _i	$V_I = V_{CC}$ or GND	5 V		1.6		1.6		pF	

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	T,	_Δ = 25°C	;	SN54L	V125A	SN74L	/125A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t pd	Α	Υ			6.8*	13*	1*	15.5*	1	15.5	
t _{en}	ŌĒ	Y	C _L = 15 pF		7*	13*	1*	15.5*	1	15.5	ns
^t dis	ŌĒ	Υ			5.1*	14.*7	1*	17*	1	17	
t _{pd}	А	Υ			8.7	16.5	15	18.5	1	18.5	
t _{en}	ŌĒ	Y	C 50 pF		8.8	16.5	70	18.5	1	18.5	20
^t dis	ŌĒ	Υ	C _L = 50 pF		7.3	18.2	& 1	20.5	1	20.5	ns
t _{sk(o)}]			2				2	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	T,	Վ = 25° C	;	SN54L	/125A	SN74L	/125A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	А	Υ			4.8*	8*	1*	9.5*	1	9.5	
t _{en}	ŌĒ	Y	C _L = 15 pF		4.8*	8*	1*	9.5*	1	9.5	ns
^t dis	ŌĒ	Υ			4.1*	9.7*	1*	11.5*	1	11.5	
^t pd	А	Υ			6.1	11.5	15	13	1	13	
t _{en}	ŌĒ	Y	C _L = 50 pF		6.2	11.5	70	13	1	13	ns
^t dis	ŌĒ	Υ	OL = 50 pr		5.5	13.2	& 1	15	1	15	115
tsk(o)						1.5				1.5	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



SN54LV125A, SN74LV125A QUADRUPLE BUS BUFFER GATES WITH 3-STATE OUTPUTS SCES124L - DECEMBER 1997 - REVISED APRIL 2005

switching characteristics over recommended operating V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1) free-air temperature range,

DADAMETED	FROM	то	LOAD	T,	Վ = 25° C	;	SN54LV	V125A	SN74L	/125A	LINUT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t pd	А	Υ			3.4*	5.5*	1*	6.5*	1	6.5	
t _{en}	ŌĒ	Y	C _L = 15 pF		3.4*	5.1*	1*	6*	1	6	ns
^t dis	ŌĒ	Υ			3.2*	6.8*	1*	8*	1	8	
t _{pd}	А	Υ			4.3	7.5	.15	8.5	1	8.5	
t _{en}	OE	Υ	C 50 pF		4.4	7.1	70	8	1	8	ns
^t dis	ŌE	Y	C _L = 50 pF		4	8.8	& 1	10	1	10	115
tsk(o)						1				1	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C (see Note 6)

	DADAMETED	SN	LINUT		
	PARAMETER				UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.4	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.3	-0.8	V
VOH(V)	Quiet output, minimum dynamic V _{OH}		3		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage	·		0.99	V

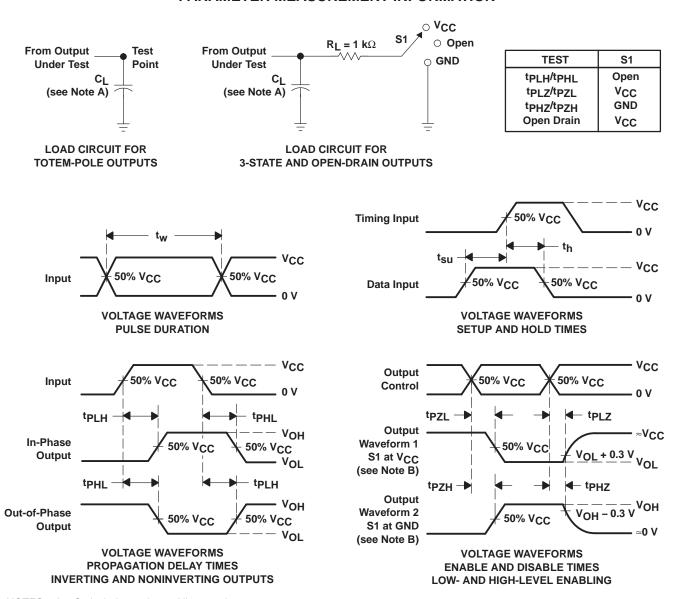
NOTE 6: Characteristics are for surface-mount packages only.

operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CO	VCC	TYP	UNIT		
C .	Dower dissination conscitones	Outpute enabled	C. F0 pF	f = 10 MHz	3.3 V	15.5	pF
Cpd	Power dissipation capacitance	Outputs enabled	$C_L = 50 \text{ pF},$	I = 10 WITZ	5 V	17.6	pΕ

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_{\Omega} = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
SN74LV125AD	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADBLE	OBSOLETE	SSOP	DB	14		TBD	Call TI	Call TI
SN74LV125ADBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADBRE4	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADGVR	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADGVRE4	ACTIVE	TVSOP	DGV	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ADRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125AN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74LV125ANE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74LV125ANSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ANSRG4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125APW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125APWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)		Level-1-260C-UNLIM
SN74LV125APWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125APWLE	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI
SN74LV125APWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125APWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125APWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
SN74LV125APWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
SN74LV125APWTE4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIN
SN74LV125APWTG4	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV125ARGYR	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAF
SN74LV125ARGYRG4	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAF



PACKAGE OPTION ADDENDUM

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⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

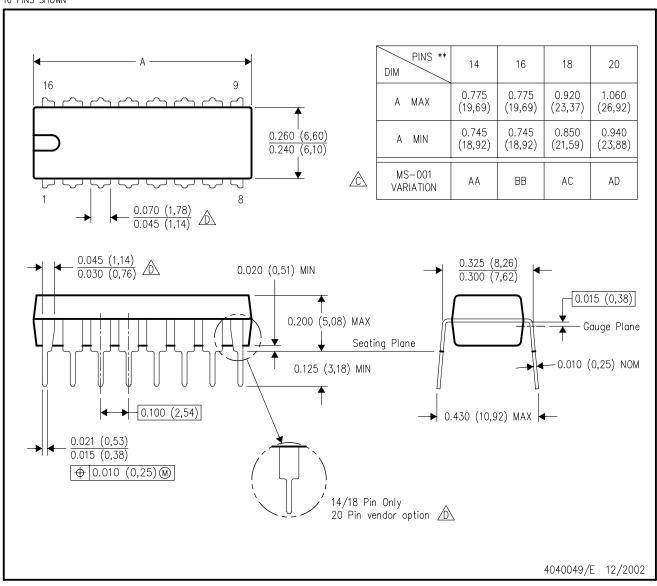
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N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



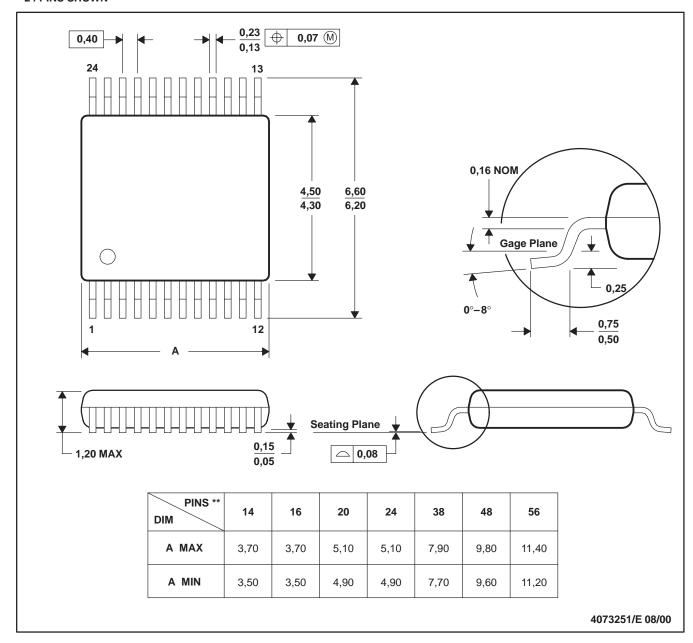
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



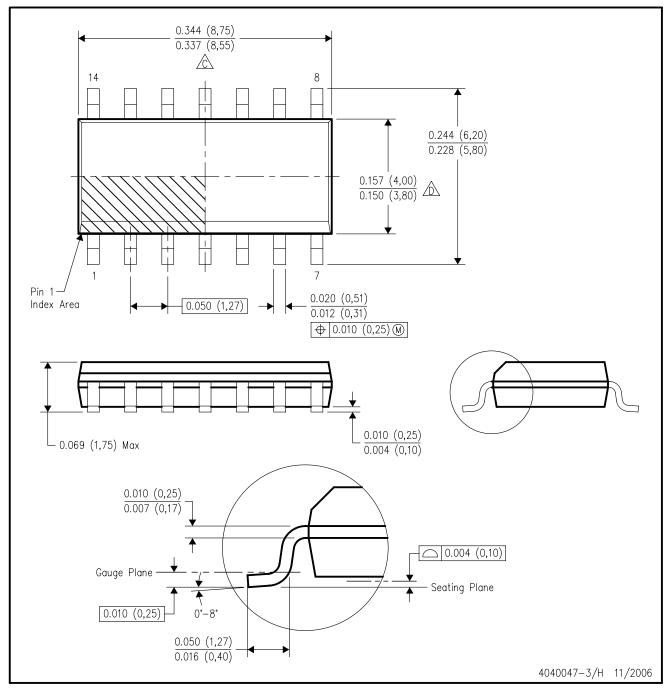
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153 14/16/20/56 Pins – MO-194



D (R-PDSO-G14)

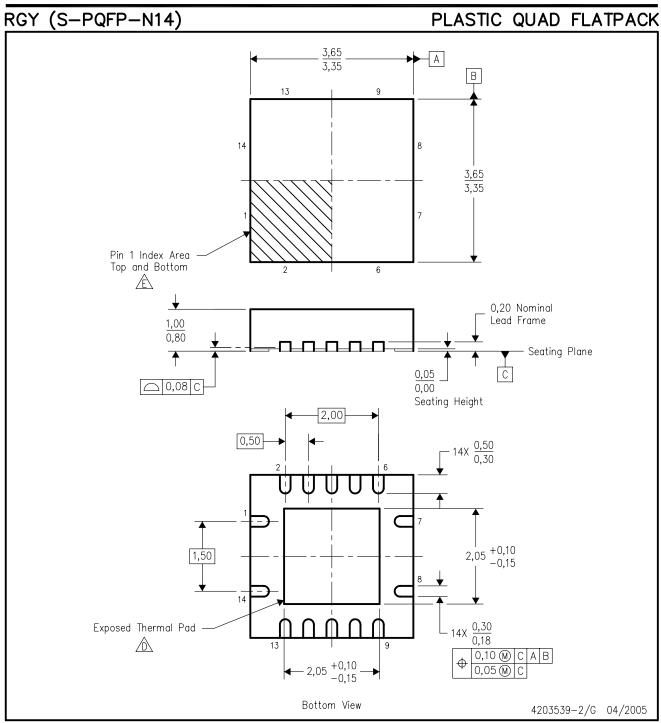
PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- $ilde{\mathbb{D}}$ The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BA.





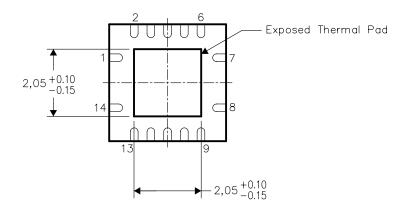
THERMAL PAD MECHANICAL DATA RGY (S-PQFP-N14)

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB), the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to a ground plane or special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No—Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

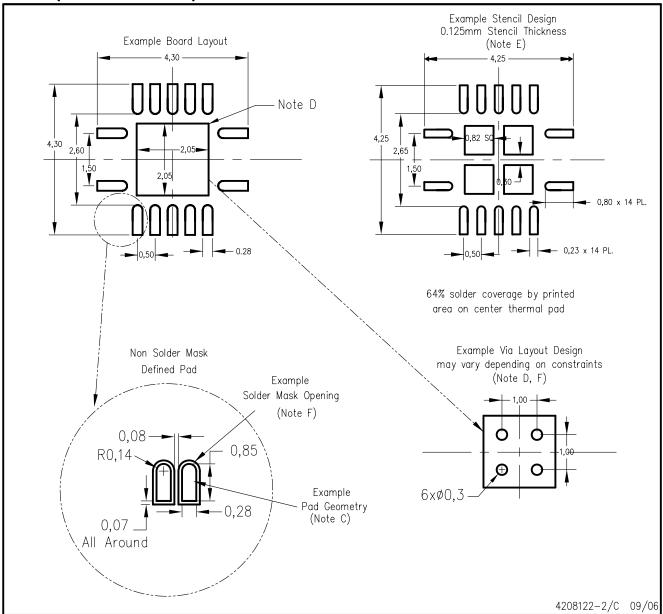


Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

RGY (R-PQFP-N14)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

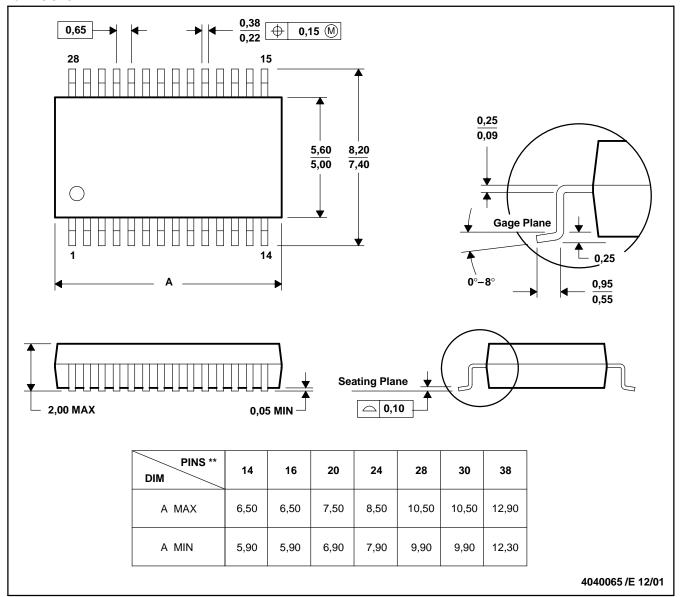
- . All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265